SARDAR PATEL UNIVERSITY

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(31 A-12)

Sixth Semester B. Sc. Examination

Under CBCS

Wednesday, 3rd April 2019

Time: 10:00 am To 01:00 pm

Subject: PHYSICS [US06CPHY05]

Digital Electronics, Electronic Communication & VLSI Technology

			Total Marks: 70
Que1		To answer the MCQs choose the correct option.	(10)
	1.	gate is equivalent to NAND gate.	
		(a) Bubbled OR (b) Bubbled AND (c) Exclusive-OR (d) Exclusive-NOR	
	2.	A string of 8 bits is called	
		(a) nibble (b) byte (c) bit (d) base	
	3.	The Boolean expression for Exclusive-OR gate is given by Y =	.•
		(a) $AB + \overline{AB}$ (b) $\overline{AB} + AB$ (c) $\overline{AB} + A\overline{B}$ (d) $\overline{AB} + \overline{BA}$	
	4.	A flip-flop is a device with stable states.	
	••	(a) one (b) two (c) three (d) none of these	
	5.	In RS-flip flop, input labelled "S" stands for	t w
		(a) systematic (b) static (c) stable (d) set	
	6,	An 8-bit ripple counter requires flip-flops.	
	•	(a) 8 (b) 16 (c) 32 (d) 4	
	7.	For ideal amplitude modulation process value of modulation index	
		(a) $m > 1$ (b) $m < 1$ (c) $m = 1$ (d) $m = 0$	
	8.	In an AM wave, the majority of the power is in	
•		(a) Carrier (b) lower sideband (c) upper sideband (d) none of these	
	9.	In LSI technology of IC fabrication, the number of logic gates on a chip are	•
	•	(a) between 100 to 10,000 (b) greater than 10,000	
		(c) between 10 to 100 (d) less than 10	
	10.	The MOS capacitor is a non polarized capacitor which can operate with	·
		(a) negative voltage (b) positive voltage	
		(c) positive or negative voltage (d) zero voltage	
			[20]
Que2		Answer briefly any ten of the following questions.	
	(1)	State the de Morgan's theorems.	
	(2)	Convert following hexadecimal numbers to binary numbers. (i) C5E2 (ii) CD42	
	(3)		
	(4)	Show the logic diagram of RS flip-flop with NAND gate.	·
			(4)

	(5)	Define: Ring counter and Ripple counter.			
	(6)	What is race condition?			
**	(7)	Why we use carrier wave in electronic communication ?			
	(8)	Define Modulation and Modulation Index.			
	(9)	Differentiate between half duplex and full duplex.			
	(10)	Give the cross sectional view of a PMOS structure fabricated on IC.			
	(11)	List out the advantages of MOS technology over bipolar technology in IC fabrication.			
	(12)	State the advantages of MOS capacitors.			
Que3	(a)	Define logic gate. Describe the working of two inputs AND gate and OR gate with suitable circuit diagram.	[06]		
	(b)	Discuss Exclusive-OR gate giving logic symbol, truth table and its application. Also implement EX-OR gate using basic gates.	[04]		
		OR			
Que3	(a)	Give the circuit diagram and working of two inputs TTL NAND gate. Also discuss the propagation delay time and power dissipation in standard TTL gate.	[06]		
	(b)	Describe the working of a NOT gate with proper circuit diagram.	[04]		
Que4	(a)	What is a flip-flop? Explain clocked RS flip-flop using proper logic diagrams and truth tables. Also discuss race condition.	[06]		
	(b)	Describe working of D flip-flop and its disadvantages.	[04]		
		OR	-		
Que4	(a)	Explain the working of 4-bit ring counter with suitable logic circuit diagram. Discuss the applications of ring counter.	[06]		
	(b)	Explain the working of 4-bit shift left register with suitable logic diagram.	[04]		
Que5	(a)	Define communication. Draw the block diagram of any communication system and explain function of each of its elements.	[06]		
	(b)	Discuss single sideband and double side band in amplitude modulation.	[04]		
		OR OR			
Que5	(a)	What is frequency modulation? With necessary diagram, explain how FM and PM differ?	[06]		
	(b)	Explain the use of varactor diode to achieve the process of frequency modulation.	[04]		
Que6		Discuss in detail, general classification of integrated circuits and different levels of integration of IC chip. Describe advantages of ICs over discrete components.	[10]		
- *		OR			
Que6		With proper diagrams, discuss monolithic planar diode, avalanche diode and Schottky diode.	[10]		